

PRODUCT SPECIFICATION

Part Number
PLBT3838D-WCIR94

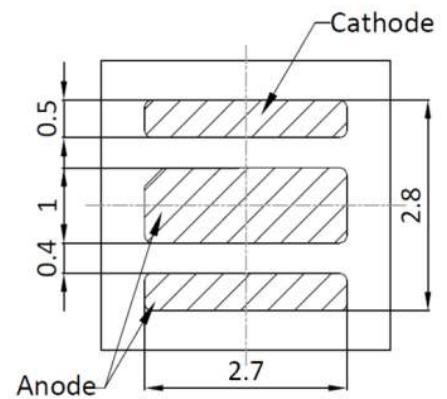
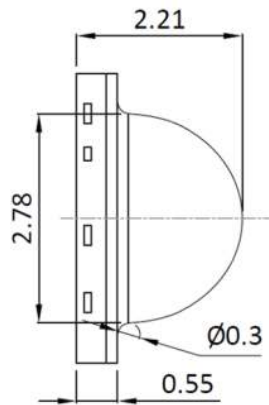
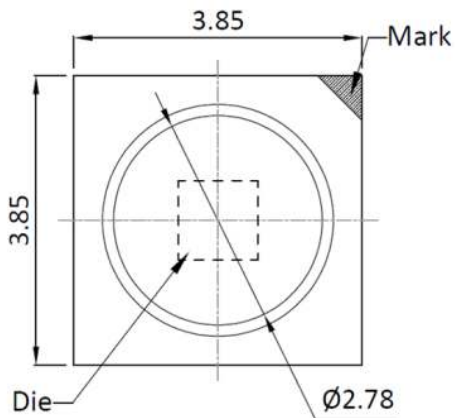
Details

- 3838 Infrared Emitter
- 3.85mm x 3.85mm x 2.21mm
- 940nm - 90° v/a
- Package: Clear Silicone

Features

- Corrosion robustness class: 3B
- ESD: 2KV (HBM: MIL-STD-883 Class 2)
- Dual junction emitter
- RoHS & REACH Compliant

Mechanical Dimensions



Notes:

1. Specifications subject to change without notice
2. All dimensions are in millimeters unless otherwise noted
3. Tolerance is ± 0.1 mm unless otherwise noted





Device Selection Guide

Model Number	Emitting Color	Lens Color	Viewing Angle
PLBT3838D-WCIR94	Infrared (IR)	Clear	90°

Notes:

- Forward voltage (VF) $\pm 0.05V$; Luminous flux (ΦV) $\pm 7\%$; CRI ± 2 ; Viewing angle($2\theta_{1/2}$) $\pm 10^\circ$
- IS standard testing.

Absolute Maximum Ratings at $T_a=25^\circ C$

Parameter	Symbol	Rating			Unit
		Min.	Typ.	Max	
Forward Current	IF	--	--	1	A
Power Consumption	Ptot	--	--	3.4	W
Reverse Voltage	Vr	--	--	5	V
Junction Temperature	TJ	--	--	145	°C
Operating Temperature Range	Topr	-40	--	100	°C
Storage Temperature Range	Tstg	-40	--	100	°C
Thermal Resistance Junction / Solder Point	RTH	--	--	12	K/W
ESD (withstand voltage (HBM : MIL-STD-883 Class 2)	VESD	--	--	2	kV

Notes:

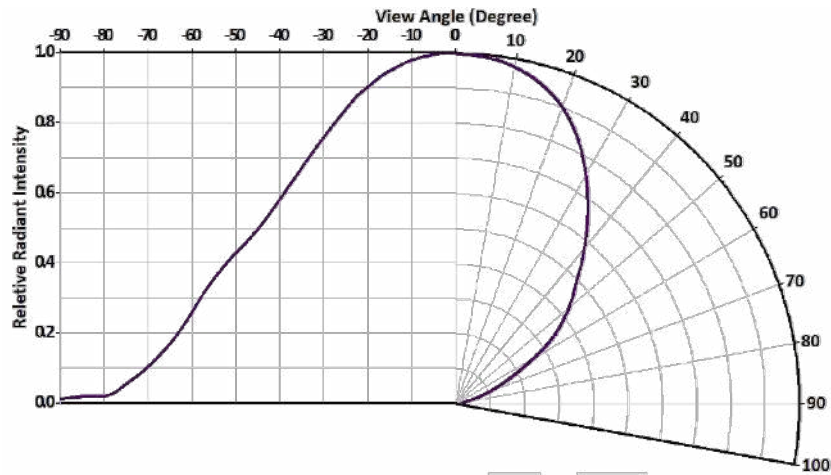
- For other ambient, limited setting of current will depend on de-rating curves.
- When drive on maximum current, Junction temperature must be kept below 145°C

Electrical Characteristics at $T_a=25^\circ C$, IF: 1A, TP: 10ms

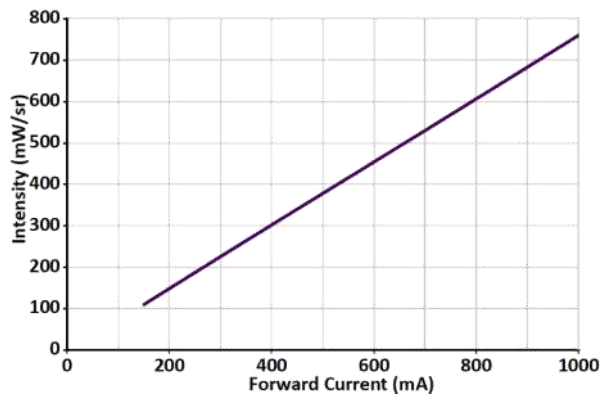
Parameter	Symbol	Rating			Unit
		Min.	Typ.	Max	
Peak Wavelength	λ_p	--	940	--	nm
Spectral Bandwidth	$\Delta\lambda$	--	25	--	nm
Viewing Angle	$2\theta_{1/2}$	--	--	90°	deg
Total Radiated Power	Φ_e	--	1300	1500	mW
Radiant Intensity	IE	--	760	--	mW/sr
Forward Voltage	VF	--	3.1	3.4	V
Reverse current (VR=5V)	IR	--	--	10	μA

Typical Electrical Optical Characteristic Curves

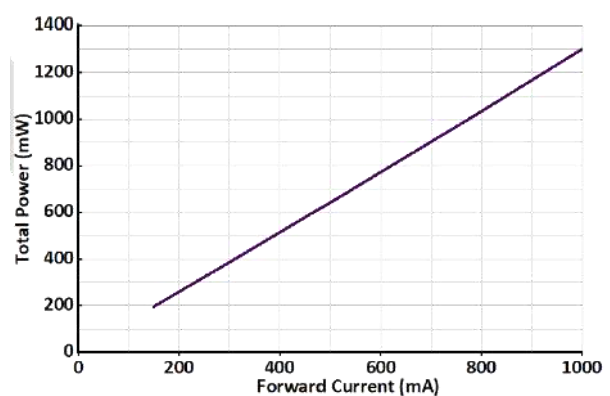
Radiation Characteristics



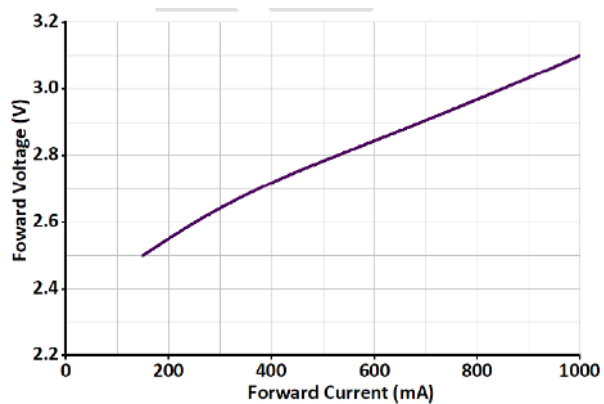
Relative Radiant Intensity



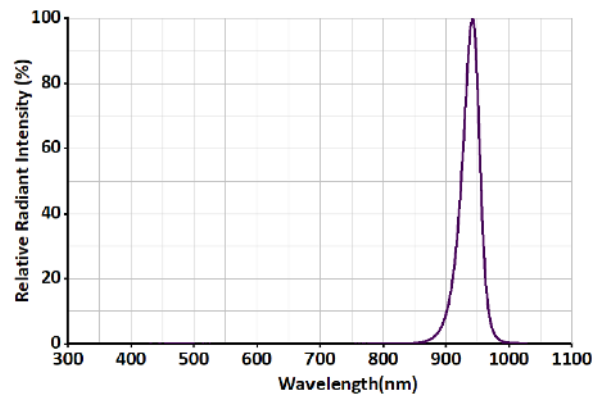
Relative Total Radiant Power



Forward Current

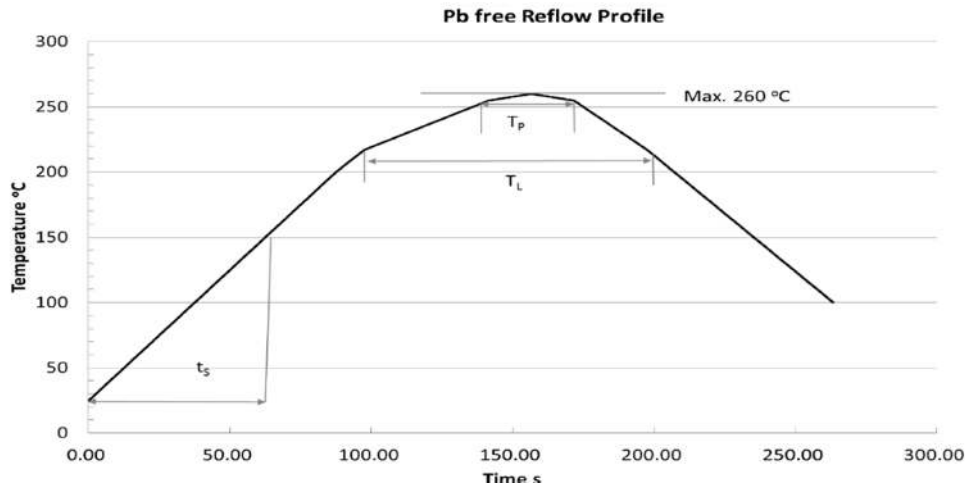


Relative Spectral Emission



Reflow Soldering Profile

Product complies to MSL Level 2 according to JEDEC J-STD-020E



Profile Feature	Symbol	Pb-Free (SnAgCu) Assembly			Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat 25 °C to 150 °C			2	3	K/s
Time t_s T_{Smin} to T_{Smax}	t_s	60	100	120	s
Ramp-up rate to peak T_{Smax} to T_P			2	3	K/s
Liquidus temperature	T_L		217		°C
Time above liquidus temperature	t_L		80	100	s
Peak temperature	T_P		245	260	°C
Time within 5 °C of the specified peak temperature T_P - 5 K	T_P	10	20	30	s
Ramp-down Rate T_P to 100 °C			3	4	K/s
Time 25 °C to T_P				480	s

1. Do not stress the silicone resin while it is exposed to high temperature.
2. The reflow process should not exceed 2 times.



PLBT3838D-WCIR94 Customer Approval Signatures	Approved By

Record of Revisions			
Rev.	Comments	Page	Date
0	Released Spec	--	6/23/22